imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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Sensors

Photointerrupter, double-layer mold type RPI-246

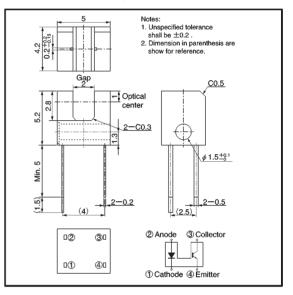
The RPI-246 is a compact, double-layer mold photointerrupter.

•Applications Floppy disk drives Movie equipment Cameras Printers

Features

- 1) Compact package based on the double-mold.
- 2) Method High resolution (slit width = 0.2 mm).
- 3) Gap between emitter and detector = 2.0 mm.

External dimensions (Units: mm)



•Absolute maximum ratings

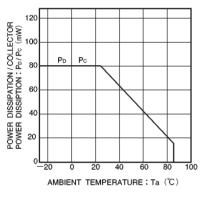
Parameter		Symbol	Limits	Unit
Input(LED)	Forward current	IF	50	mA
	Reverse voltage	VR	5	V
	Power dissipation	PD	80	mW
Output (photo- (transistor)	Collector-emitter voltage	VCEO	30	V
	Emitter-collector voltage	VECO	4.5	V
	Collector current	lc	30	mA
	Collector power dissipation	Pc	80	mW
Operating temperature		Topr	-25~+85	ĉ
Storage temperature		Tstg	-30~+85	Ĵ

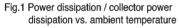


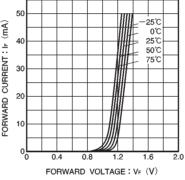
			,				
Parameter		Symbol	Min.	Тур.	Max.	Unit	Conditions
Input charac- teristics	Forward voltage	VF	—	1.3	1.6	V	I⊧=50mA
	Reverse current	IR		—	10	μA	V _R =5V
Output charac- teristics	Dark current	ICEO	_	_	0.5	μA	V _{CE} =10V
	Peak sensitivity wavelength	λp	_	800	-	nm	_
Transfer charac- teristics	Collector current	lc	0.35	_	1.2	mA	VcE=5V, IF=20mA
	Collector-emitter saturation voltage	VCE(sat)	_	_	0.4	v	I⊧=20mA, Ic=0.2mA
	Response time	tr∙tf	_	10	_	μs	$V_{CC}=5V$, IF=20mA, RL=100 Ω

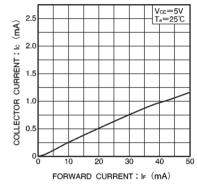
Electrical and optical characteristics (Tc = 25° C)

Electrical and optical characteristic curves









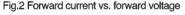
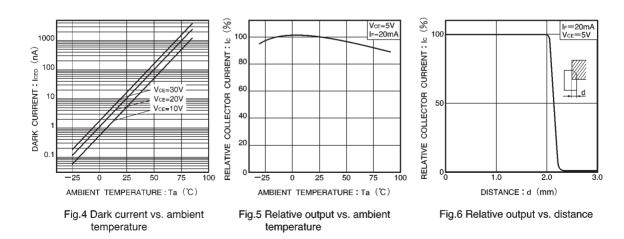
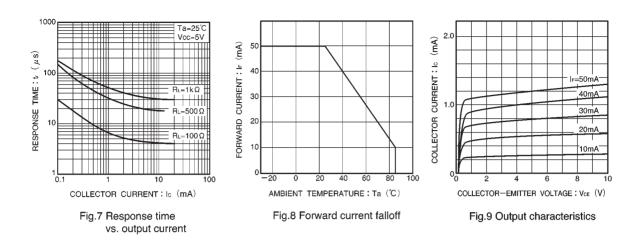
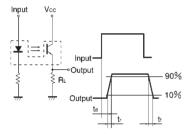


Fig.3 Collector current vs. forward current







ta: Delay time

 $t_{r}.\mbox{Rise time}$ (time for output current to rise

from 10% to 90% of peak current) tr Fall time (time for output current to fall

from 90% to 10% of peak current)

Fig.10 Response time measurement circuit

